

## SPICE Device Model SiR466DP Vishay Siliconix

## N-Channel 30-V (D-S) MOSFET

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

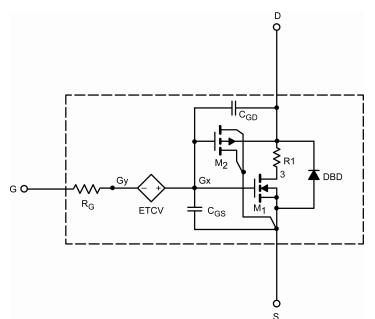
- · Apply for both Linear and Switching Application
- Accurate over the 55 °C to 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### DESCRIPTION

The attached spice model describes the typical electrical characteristics of the N-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55  $^{\circ}$ C to 125  $^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

# A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.



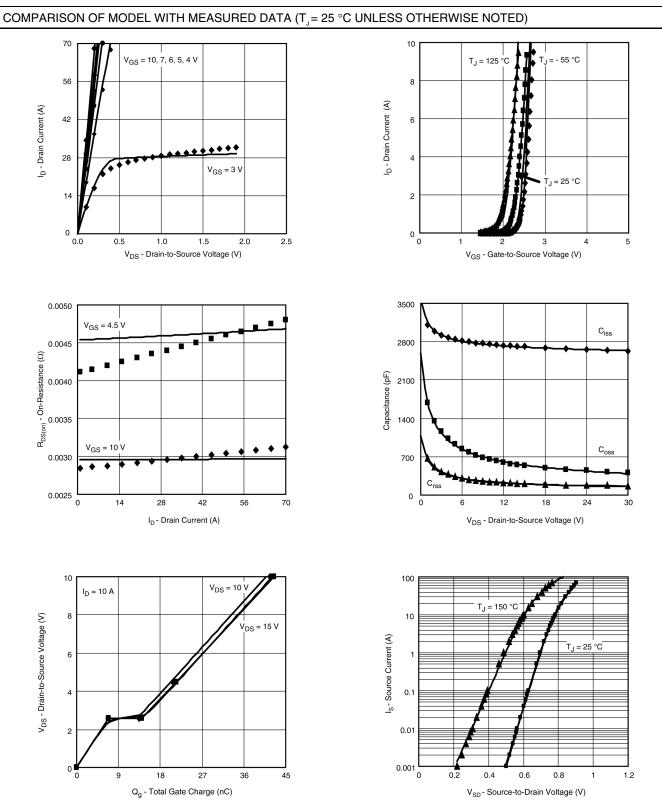
SPECIFICATIONS (T, = 25 °C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{_{DS}} = V_{_{GS}}, I_{_{D}} = 250 \ \mu A$	1.5		V
Drain-Source On-State Resistance <sup>a</sup>	$R_{\scriptscriptstyle DS(on)}$	$V_{_{\rm GS}} = 10$ V, $I_{_{\rm D}} = 15$ A	0.0029	0.0029	Ω
		$V_{_{\mathrm{GS}}} = 4.5 \text{ V}, \text{ I}_{_{\mathrm{D}}} = 10 \text{ A}$	0.0045	0.0042	
Forward Transconductance <sup>a</sup>	<b>g</b> <sub>fs</sub>	$V_{_{DS}} = 15 \text{ V}, \text{ I}_{_{D}} = 15 \text{ A}$	59	65	S
Body Diode Voltage	V <sub>sd</sub>	I <sub>s</sub> = 3 A	0.73	0.74	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	$V_{_{DS}}$ = 15 V, $V_{_{GS}}$ = 0 V, f = 1 MHz	2730	2700	pF
Output Capacitance	C <sub>oss</sub>		548	540	
Reverse Transfer Capacitance	C <sub>rss</sub>		205	205	
Total Gate Charge	Q <sub>g</sub>	$V_{_{\rm DS}}$ = 15 V, $V_{_{\rm GS}}$ = 10 V, $I_{_{\rm D}}$ = 10 A	42	42.5	nC
		$V_{_{DS}} = 15 \text{ V}, \text{ V}_{_{GS}} = 4.5 \text{ V}, \text{ I}_{_{D}} = 10 \text{ A}$	21	21.5	
Gate-Source Charge	Q <sub>gs</sub>		6.9	6.9	
Gate-Drain Charge	Q <sub>gd</sub>		7.1	7.1	

Notes

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.



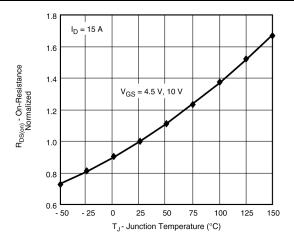
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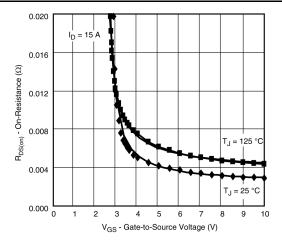


Note: Dots and squares represent measured data.

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COMPARISON OF MODEL WITH MEASURED DATA (T = 25 °C UNLESS OTHERWISE NOTED)





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Note: Dots and squares represent measured data.

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## Disclaimer

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